

The IC SeNOB 2016 was held in Rzeszow, Poland on May 22-25, 2016.

Participants' contributions were presented and discussed over 7 concurrent sessions:

- A** – MBE growth of II-VI and III-V nanostructures (QW, MQW, QWires) for optoelectronics and biosensors
- B** - Characterisation of II-VI and III-V nanostructures (optical properties and electron transport);
- C** – Applications for optoelectronics (photovoltaics, IR- and Thz- detectors, lasers);
- D** – Topological Insulators;
- E** – Applications for quantum logics;
- F** – Biosensors based on II-VI and III-V nanostructures;
- G** – Numeric methods and simulation for characterization of II-VI and III-V nanostructures (optical properties and electron transport),

The conference was attended by 113 registered participants (16 scientific sessions, 47 speakers, 38 posters; 14 plenary speakers, 18 invited speakers and 17 speakers presented the conference scientific papers) from 12 countries in Europe, America and Asia as well as 34 guests from the authorities of the University of Rzeszow and representatives of regional authorities (by Marshal's Office, deputy of the Polish Parliament), and representatives of cooperating with the University businesses and companies representing the airline industry, colleagues from the Faculty of Mathematics and Natural Sciences and the Faculty of Biology and Agriculture, and others.

There were presented the results of the achievements of scientific research conducted by the research teams. More information about the program and conference speakers you can find on the website: http://nano.rzeszow.pl/general_information.php